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<u>Vishay Semiconductor/Diodes Division</u> <u>VS-HFA16PA60CPBF</u>

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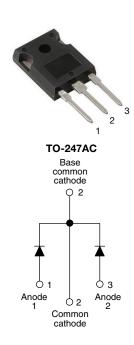
Datasheet of VS-HFA16PA60CPBF - DIODE ARRAY GP 600V 8A TO247AC Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



VS-HFA16PA60CPbF, VS-HFA16PA60C-N3

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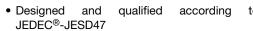
HEXFRED® Ultrafast Soft Recovery Diode, 2 x 8 A

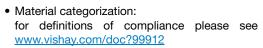


PRODUCT SUMMARY						
TO-247AC						
2 x 8 A						
600 V						
1.4 V						
18 ns						
150 °C						
Common cathode						

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}









ROHS
COMPLIANT
HALOGEN
FREE
Available

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

VS-HFA16PA60C... is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 8 A per leg continuous current, the VS-HFA16PA60C... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA16PA60C... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Cathode to anode voltage	V _R		600	V		
Maximum continuous forward current per leg	1	T _C = 100 °C	8			
per device	IF	1 _C = 100 C	16			
Single pulse forward current	I _{FSM}		60	А		
Maximum repetitive forward current	I _{FRM}		24			
Maximum nawar dissination	В	T _C = 25 °C	36	W		
Maximum power dissipation	P_{D}	T _C = 100 °C	14	VV		
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C		

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ELECTRICAL SPECIFICATIONS PER LEG (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V_{BR}	Ι _R = 100 μΑ		600	-	-		
	imum forward voltage $V_{FM} = \begin{array}{c} I_F = 8.0 \text{ A} \\ I_F = 16 \text{ A} \\ I_F = 8.0 \text{ A}, T_J = 125 \text{ °C} \end{array}$ Se		-	1.4	1.7	V		
Maximum forward voltage		I _F = 16 A	See fig. 1	-	1.7	2.1	-	
		I _F = 8.0 A, T _J = 125 °C		-	1.4	1.7		
Maximum reverse	1	V _R = V _R rated	See fig. 2	-	0.3	5.0		
leakage current	I _{RM}	T _J = 125 °C, V _R = 0.8 x V _R rated	See fig. 2	-	100	500	μΑ	
Junction capacitance	C _T	V _R = 200 V	See fig. 3	-	10	25	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body - 8.0			-	nH		

DYNAMIC RECOVERY CHARACTERISTICS PER LEG (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A}$	$A/\mu s$, $V_R = 30 V$	-	18	-		
Reverse recovery time See fig. 5, 6 and 16	t _{rr1}	T _J = 25 °C		-	37	55	ns	
dee lig. 3, 6 and 16	t _{rr2}	T _J = 125 °C		-	55	90		
Peak recovery current See fig. 7 and 8	I _{RRM1}	T _J = 25 °C	$I_F = 8.0 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	-	3.5	5.0	Α	
	I _{RRM2}	T _J = 125 °C		-	4.5	8.0		
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	65	138	nC	
See fig. 9 and 10	Q _{rr2}	T _J = 125 °C		-	124	360	iiC	
Peak rate of fall recovery current during t _b See fig. 11 and 12	dI _{(rec)M} /dt1	T _J = 25 °C		-	240	-	- A/μs	
	dI _{(rec)M} /dt2	T _J = 125 °C		-	210	-	Ανμο	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C	
Junction to case, single leg conducting			-	-	3.5		
Junction to case, both leg conducting	R _{thJC}		-	-	1.75	14004	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	- K/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.25	-		
Majalat			-	6.0	-	g	
Weight			-	0.21	-	OZ.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-247AC (JEDEC)	HFA16PA60C				

Revision: 10-Jul-15 2 Document Number: 94056



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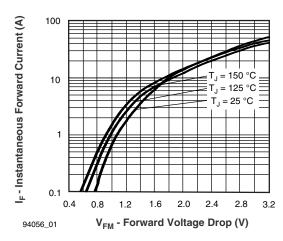


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)

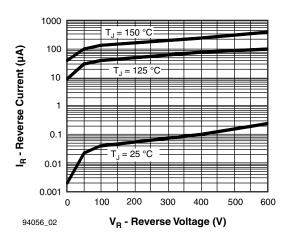


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

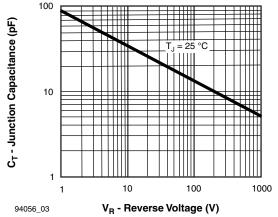


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

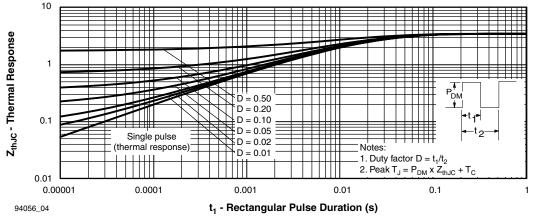


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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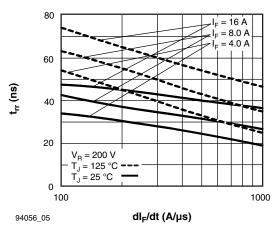


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt (Per Leg)

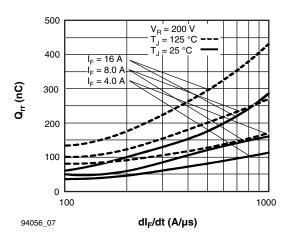


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)

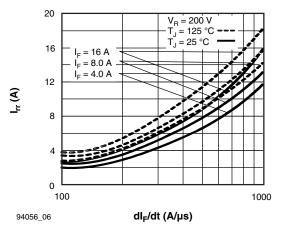


Fig. 6 - Typical Recovery Current vs. dI_F/dt (Per Leg)

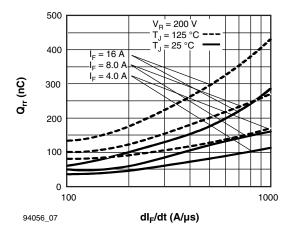


Fig. 8 - Typical dI_{(rec)M}/dt vs. dI_F/dt (Per Leg)

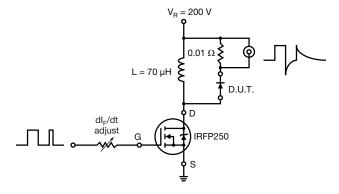


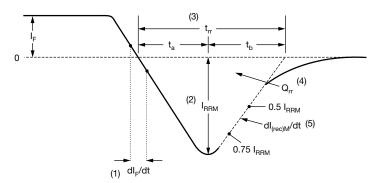
Fig. 9 - Reverse Recovery Parameter Test Circuit



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- (1) dl_E/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $t_{\rm rr}$ reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}

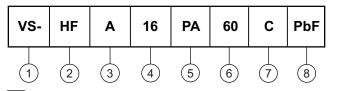
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- HEXFRED® family
- Electron irradiated
- Current rating (16 = 16 A)
- PA = TO-247AC
- Voltage rating: (60 = 600 V)
- Circuit configuration

C = Common cathode

8 Environmental digit:

PbF = lead (Pb)-free and RoHS-compliant

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-HFA16PA60CPbF	25	500	Antistatic plastic tube				
VS-HFA16PA60C-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95542			
Part marking information	TO-247ACPbF	www.vishay.com/doc?95226			
Fait marking imormation	TO-247AC-N3	www.vishay.com/doc?95007			

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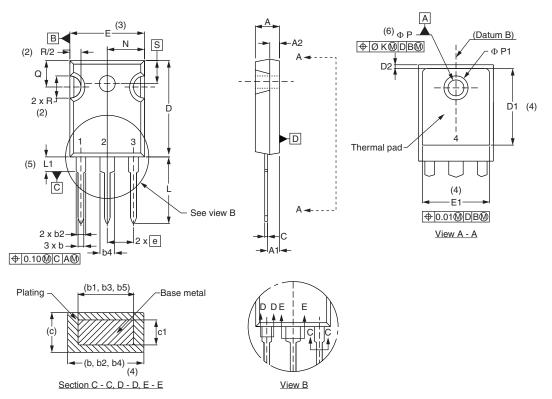


Outline Dimensions

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TO-247 - 50 mils L/F

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STWIDGE	MIN.	MAX.	MIN.	MAX.	NOILS
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

1	NAUL L INA	IETEDO	INC	LIEC	
SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
D2	0.51	1.35	0.020	0.053	
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215 BSC		
ØK	0.254		0.010		
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62 BSC		0	.3	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	7.39	-	0.291	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	'BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q

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